The NaI:Tl and CsI:Tl crystals for effective detection of X-rays and low energy charged particles

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What is our typical view on NaI(TI) crystal?



Dimensions from diam.10×10 mm

to diam. 500×500 mm

Energy resolution 5.6% @ 662 keV (137Cs)

Typical energy range from 17 keV

to more than 10 MeV

Light yield about 40 000 ph/MeV (gamma)

What will change if we are looking for low energy events?

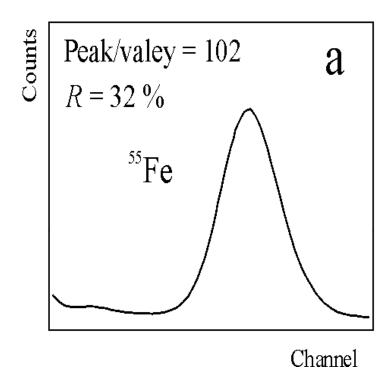
The best energy resolution -32% @ 5.9 keV of 55 Fe

Improved non-proportionality at low energy

Different quenching factor for different particle type

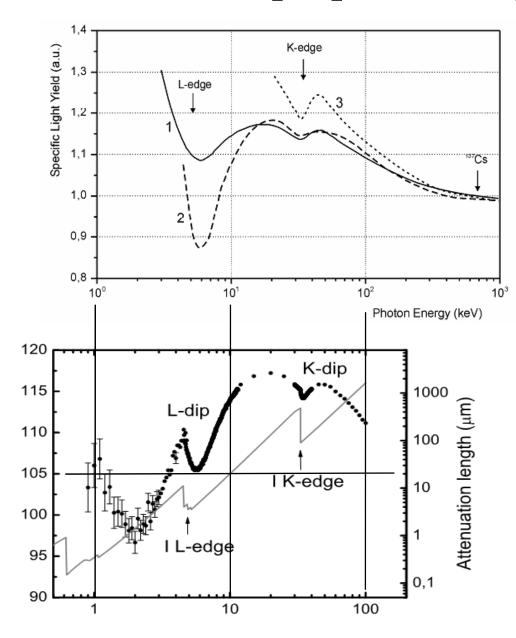
Detection of Soft X-rays by NaI:Tl Crystal

(Persik D.E., Moi T.E., IEEE Trans. Nucl. Sci. – 1978. - Vol. NS-25, 615)



Pulse height spectrum of NaI:Tl crystal at excitation by ⁵⁵Fe isotope (a) with 5.9 keV energy. Peak at 1.5 keV on part *b* arises from interaction of X-rays in collimator.

Non-proportionality of Response



Aitken D.W., et al. IEEE TNS, NS-14, 1967.

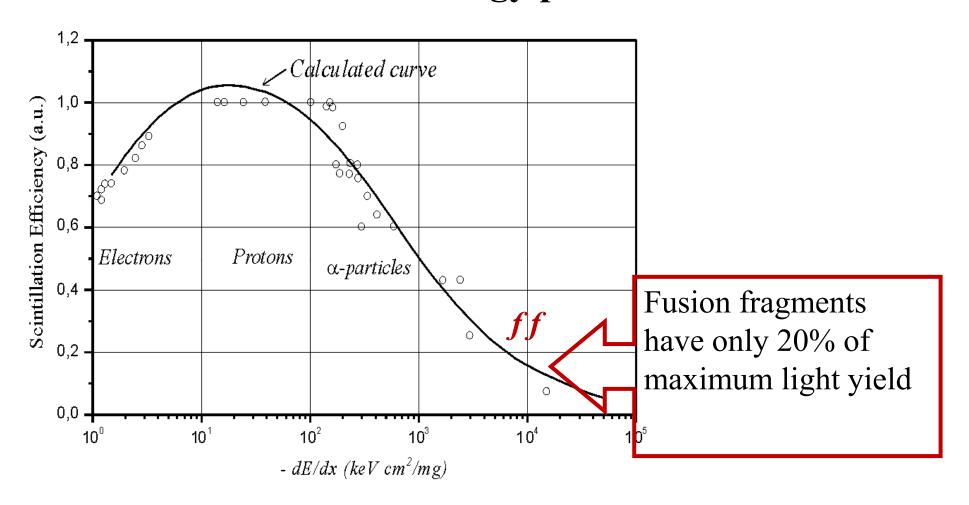
1 - NaI:Tl;

2 - CsI:Tl;

3 - CsI:Na.

I. Khodyuk, P. Dorenbos, IEEE TNS, 2012

Problems of low energy particle detection



How to solve all these problems in framework of DM particles search?

our experimental goals

expected events in the energy range of 3–10 keV As low as possible energy threshold As high as possible energy resolution As high as possible light yield proportionality



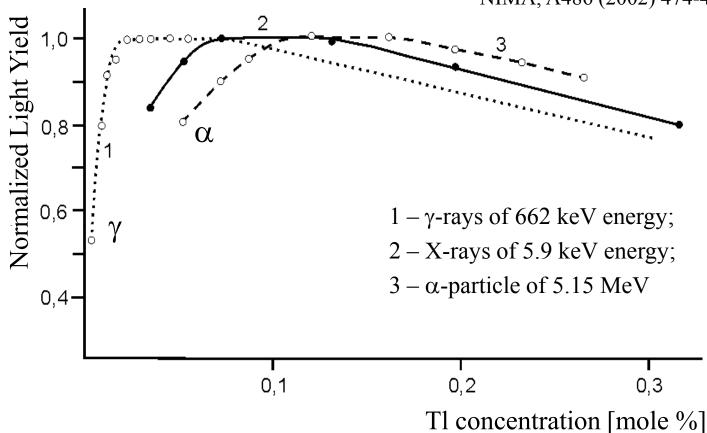
All these requirements could be satisfied
Only by crystals grown in dedicated conditions
Different from conditions for common crystal application

One of possible solution

Find optimum Tl concentration for detection of heavy charged particles

Optimum Tl concentration (C_{Tl}^*) in NaI:Tl

Trefilova L.N., Kudin A.M., et all., NIMA, A486 (2002) 474-481.



$$C_{Tl}^* = 2.2 \cdot 10^{-2} \%$$
 for γ -rays;

 $C_{Tl}^* = 7.3 \cdot 10^{-2} \%$ for soft X-rays of 5.9 keV;

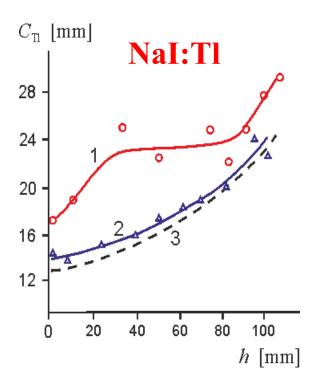
 $C_{\text{Tl}}^* = 1.3 \cdot 10^{-1} \%$ for α -particles.

 $C_{\rm Tl}^* > 0.15$ % for ion detection

Impurity distribution in crystal grown by Bridgman-Stockbarger technique

$$C_{\text{Tl}} = C_0 k_0 \left(1 - \frac{V}{V_0} \right)^{k_0 - 1}$$

 $k_{\rm o}$ – equilibrium segregation coefficient $C_{\rm o}$ – initial concentration



1 – crystal growth in vacuum;

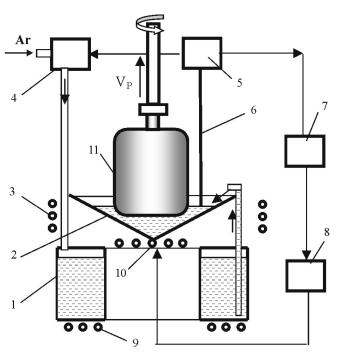
2 - crystal growth in oxygen;

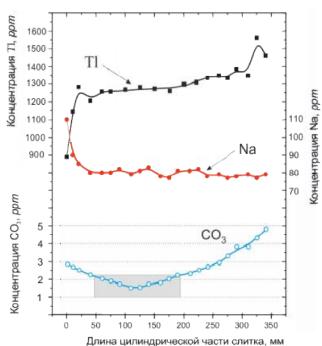
3 – calculated curve for $k_0 = 0.25$ $C_0 = 0.36 \%$

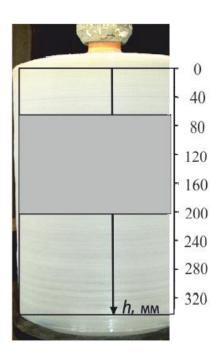
In heavily doped crystal activator is distributed non-uniformly It can not be described by Pfann rule

NaI:Tl crystal for particle detection: homogeneity

Furnace for crystal growth with conical crucible "Crystal-400"







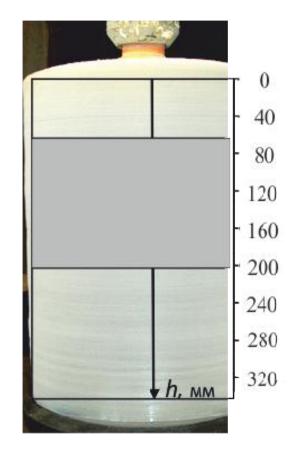
Distribution of Tl in scintillation material CsI:Tl along height

Uniformity of spectrometric parameters

CsI:Tl photodiode scintillators of 1 cm³.

12 sample from selected region.

#	¹³⁷ Cs @ 662 keV		²⁴¹ Am @ 59.6 keV	
	L	R, %	L	R, %
1	3020	5.92	307	37.58
2	3036	5.97	302	38.2
3	3075	5.9	308	37.46
4	3047	5.87	309	37.34
5	3105	5.61	311	37.1
6	3000	5.8	302	38.2
7	3090	5.49	309	37.34
8	3079	5.5	308	37.46
9	3082	5.5	308	37.46
10	3070	5.83	309	37.34
11	3069	5.83	310	37.22
12	3078	5.81	311	37.1

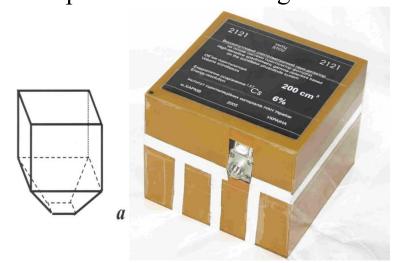


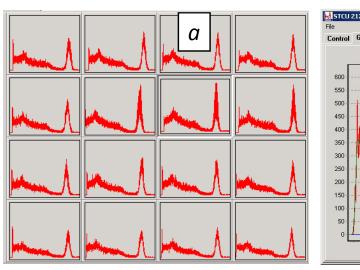
Uniformity of spectrometric parameters

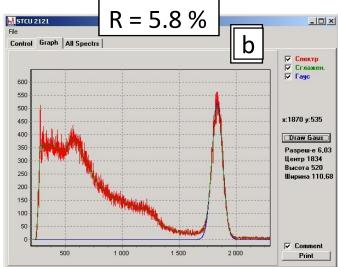
Photodiode scintillator of 200 cm³. 16 sample from selected region.

Pulse height spectra for each element (left) and summarized spectrum of whole block (right).

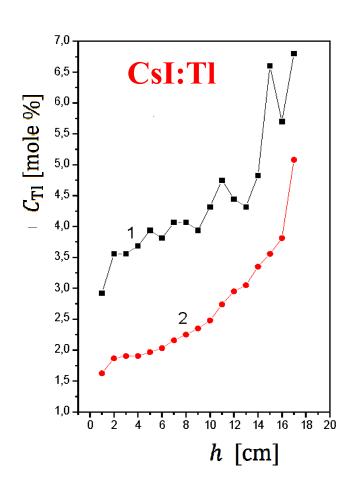
 $V = 216 \text{ cm}^3$.







Non-homogeneous microscopic distribution of Tl in heavily activated CsI:Tl crystal



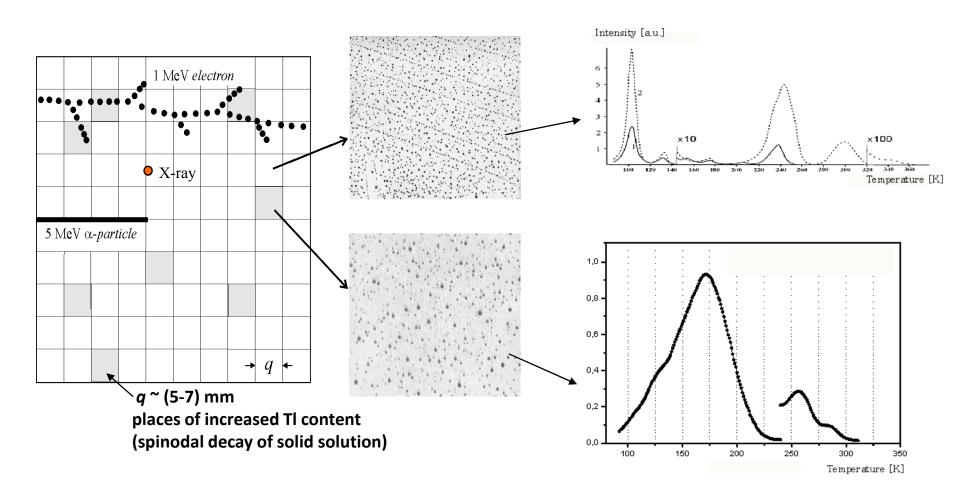
PIXE analysis results

Brand	CsI	Nominal Tl	Measured Tl	Type of
	n.	conc.(ppm)	conc. (ppm)	measure
GB	1	4000	6400±200	Face A, av
GB	1	4000	9300±300	Face A, point
GB	1	4000	5400±200	Face A, point
GB	1	4000	6100±200	Face B, av
GB	1	4000	4610±180	Side, av
GB	2	3000	2950±110	Face A, av
GB	2	3000	4900±200	Face B, point
GB	2	3000	3030±120	Face B, av
St. Gobain	3	500	440±50	Face A, av
St. Gobain	4	200	280±30	Face A, av
Marketech	-5	700	520±30	Face A, av
Scionix	-6	2500	5220±160	Face A, av

FAZIA collaboration results

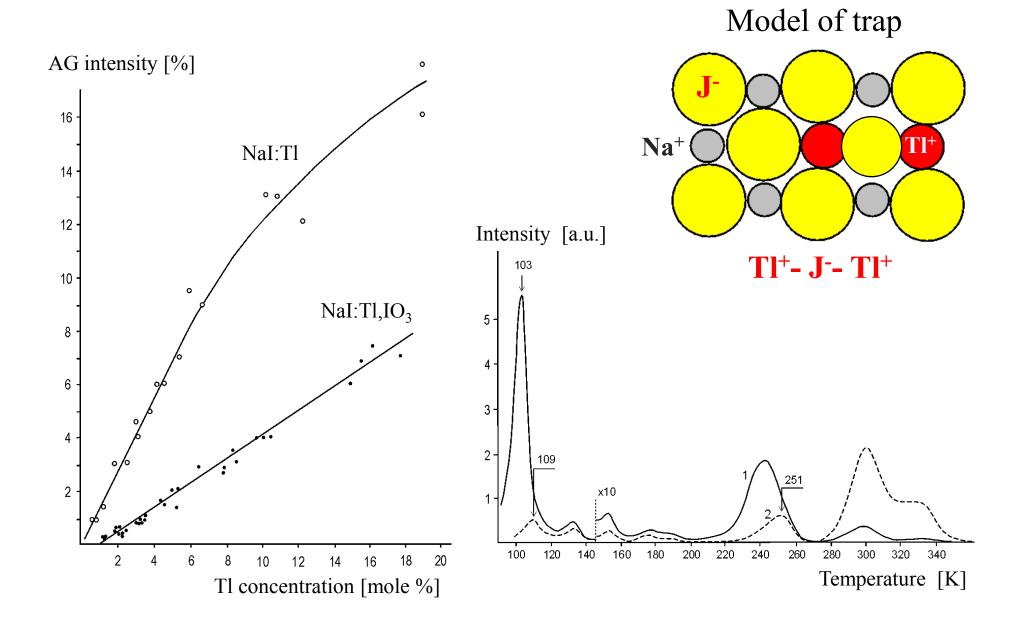
In $C_{TI} > 0.15\%$ the activator is not homogeneous distributed both macroscopically and microscopically

Nature of concentration quenching (CQ) Heavily activated NaI:Tl crystal corresponds to region of CQ

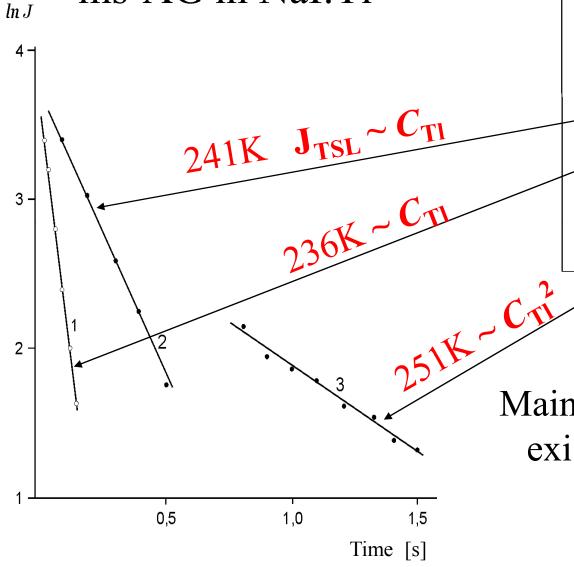


Schematic image of microscopic distribution of Tl⁺ center in CsI crystal at high Tl concentration. Photo represents the character of decoration of the cleavage plane in two different places.

Nature of millisecond afterglow

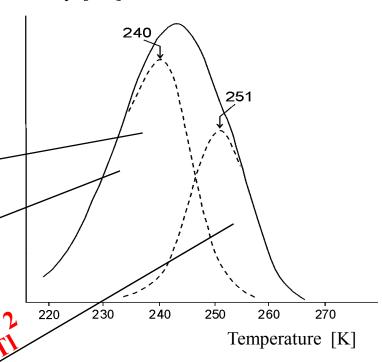


Two components of ms-AG in NaI:Tl



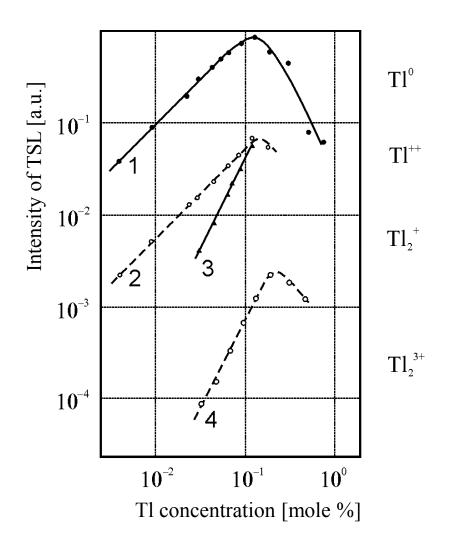
Two peaks of TSL

Intensity [a.u.]

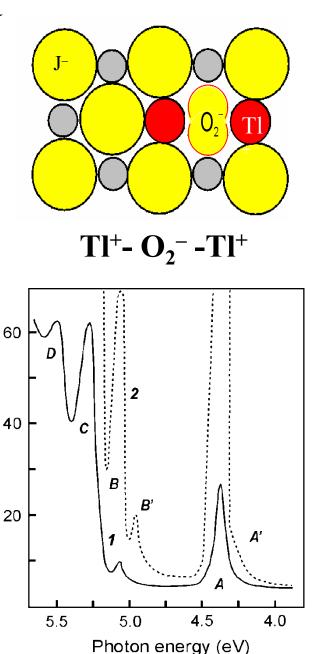


Main reason of ms-AG is an existence of stable $(Tl^+)_2$ centers

Nature of millisecond afterglow and mechanism of its suppressing

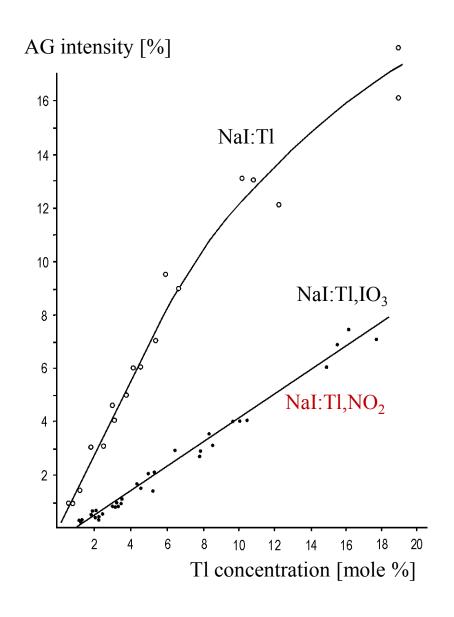


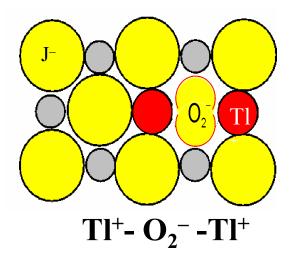
Oxygen suppress AG and LY



Absorption coefficient (cm⁻¹)

Reason of afterglow suppression by O₂⁻ and NO₂⁻



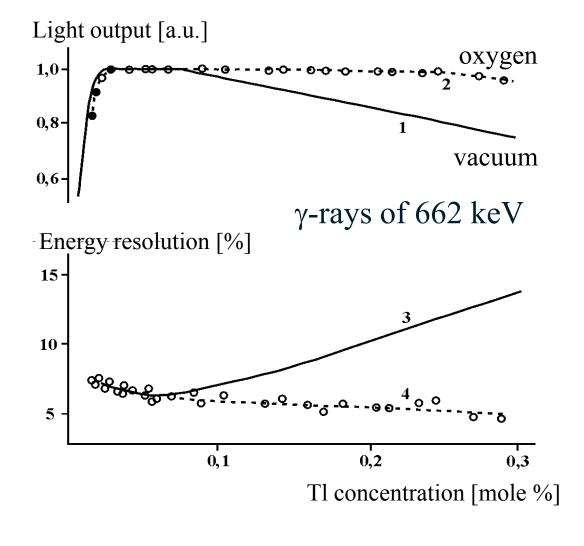


Model of non-luminescence center



The same for nitrate ion NO₂⁻

NaI:Tl,IO₃ crystals without CQ

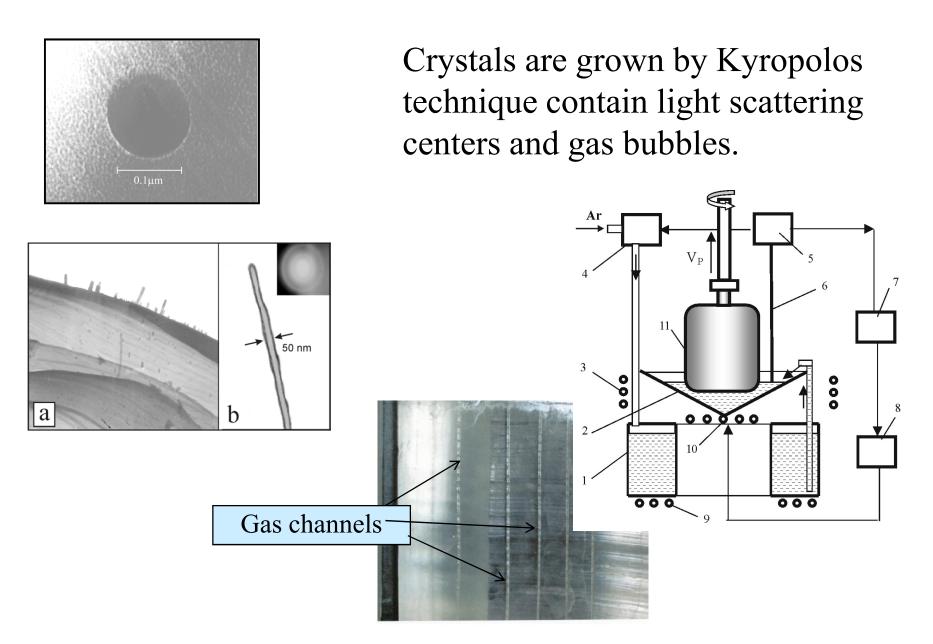


Crystal are grown by Bridgman-Stockbarger technique in oxygen atmosphere:

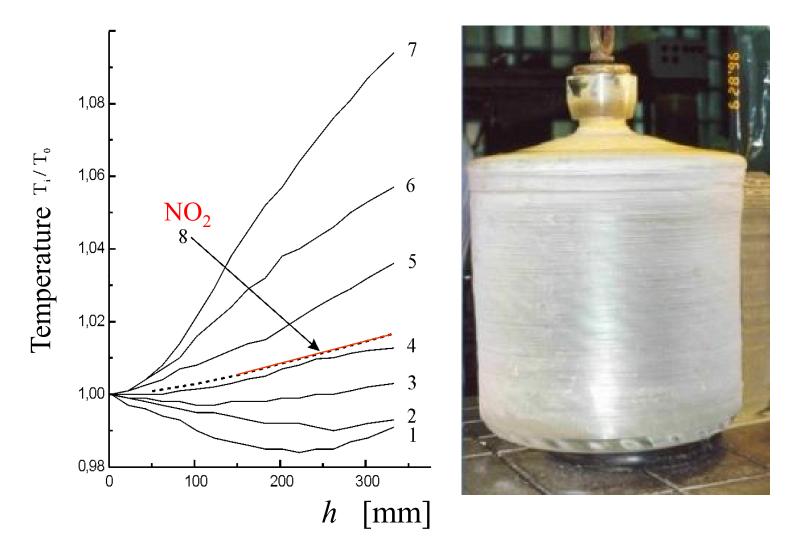
$$NaIO_3 = NaI + 3/2 O_2$$

- good stirring of the melt;
- good transparency;
- low level of ms-AG;
- min-AG is absent;
- light scattering and gas bubbles are absent.

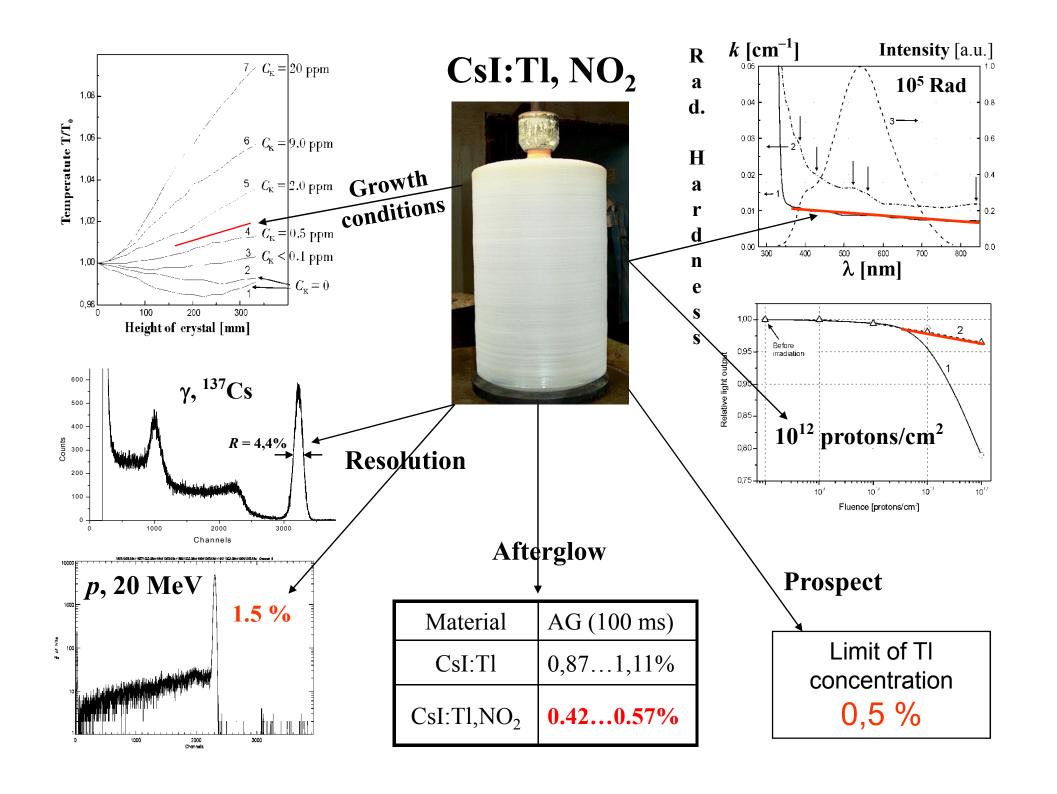
Disadvantages of NaI:Tl,IO₃ crystals



Crystal growth of uniform and heavy-activated ingot



Scintillation material: NaI:Tl,CO₃ or CsI:Tl,CO₃



Summary

The same results as for CsI(TI,NO₂) can be achieved also for heavily doped NaI(TI,NO₂) single crystals (TI concentration > 0.15 mol.%)

- 1. Big volume crystals (diameter more than 100 mm)
- 2. High optical transmittance
- 3. High uniformity of dopant distribution
- 4. High energy resolution, both for 662 keV and 5.9 keV gammas
- 5. Optimal quenching factor for heavy charged particle
- 6. Without concentration quenching for gamma rays
- 7. Low millisecond/minute scale afterglow

Production of heavily doped NaI(TI,NO₂) single crystals (TI concentration > 0.15 mol.%) required dedicated growth technology and knowledge

Small volume heavily doped NaI(TI,NO₂) single crystals are available for testing

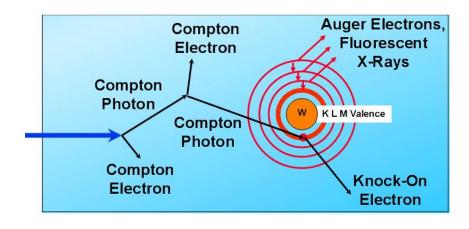
Large volume heavily doped NaI(TI,NO₂) single crystals should be grown

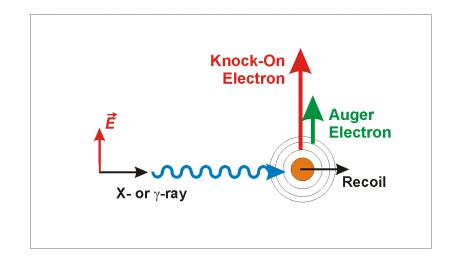


Cascade only (Auger electrons and X-ray) Conclusions do not increase Dep. L vs C_{T1} dE/dxDecay time Resolution Cascade + Photoelectron of ~ 1 keV energy increase dE/dxСветовой выход, отн.ед. L-edge 0,4-10 0,1 0,3 0,2 Energy (keV)

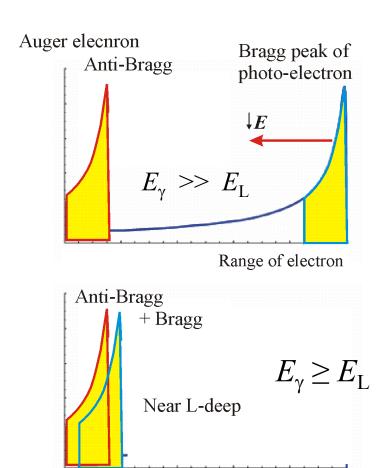
Tl concentration [mole %]

Anti-Bragg peak at place of photoelectron birth



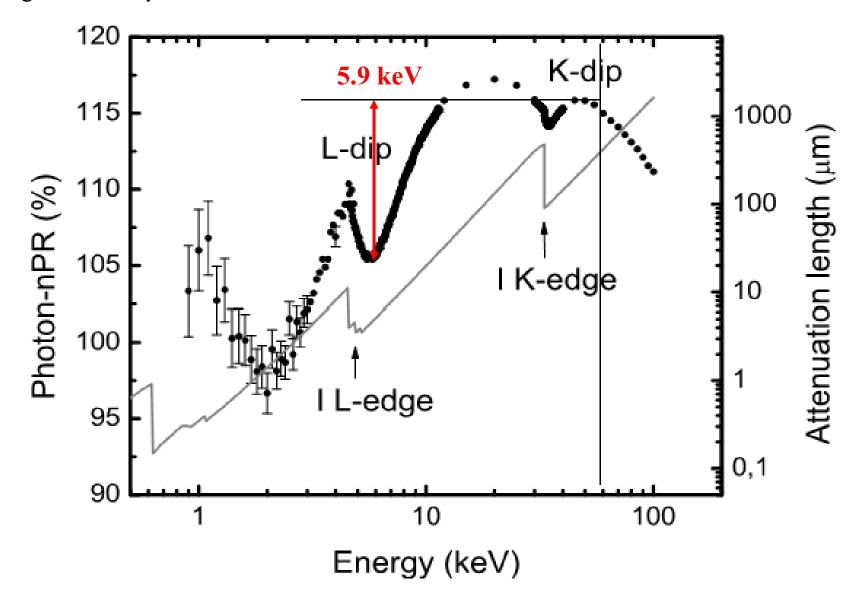


Nucleus receives recoil pulse Direction of electron coincides with \overrightarrow{E}



Energy loss dE/dx is increased \sim twice near L-edge

Range of electron



A point 5,9 keV can be lifted from 106 to 116% if $C_{\rm Tl} > 7.3 \cdot 10^{-2}$ mole%

Simplified Cascade Diagram for Nal

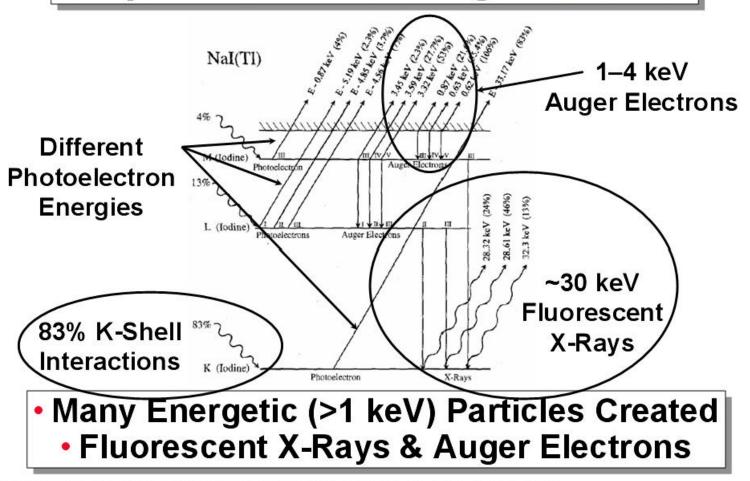


Figure from B.D. Rooney & J.D. Valentine, IEEE Trans. Nucl. Sci. 44, pp. 509-516, 1997

Application of Living Layer to Theory Verification

